

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7MZ157FK

Low Voltage Quad 2-Channel Multiplexer With 5V Tolerant Inputs And Outputs

The TC7MZ157 is a high performance CMOS MULTIPLEXER. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

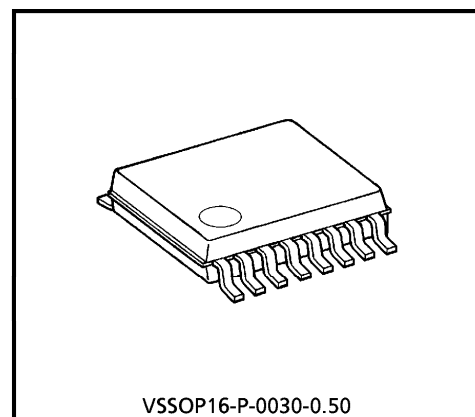
The device is designed for low-voltage (3.3V) V_{CC} applications, but it could be used to interface to 5V supply environment for inputs.

It consists of four 2-input digital multiplexers with common select and strobe inputs.

When the \overline{STROBE} input is held "H" level, selection of data is inhibited and all the outputs become "L" level.

The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.



VSSOP16-P-0030-0.50

Weight: 0.02g (Typ.)

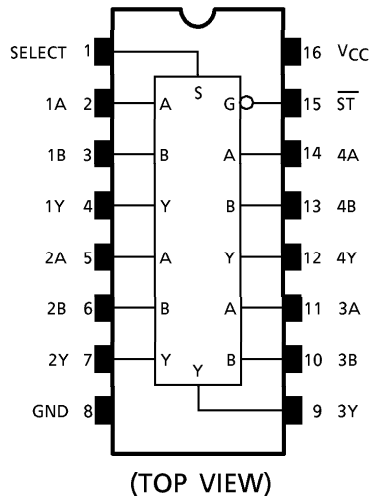
Features

- Low voltage operation: $V_{CC} = 2.0 \sim 3.6V$
- High speed operation : $t_{pd} = 6.0ns$ (max) ($V_{CC} = 3.0 \sim 3.6V$)
- Output current : $|I_{OH}| / I_{OL} = 24mA$ (min)
($V_{CC} = 3.0V$)
- Latch-up performance : $\pm 500mA$
- Available in VSSOP (US16)
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 157 type.

980910EBA2

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Pin Assignment

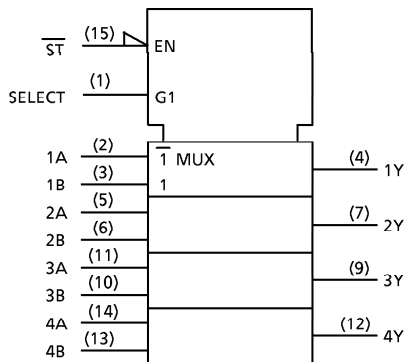


Truth Table

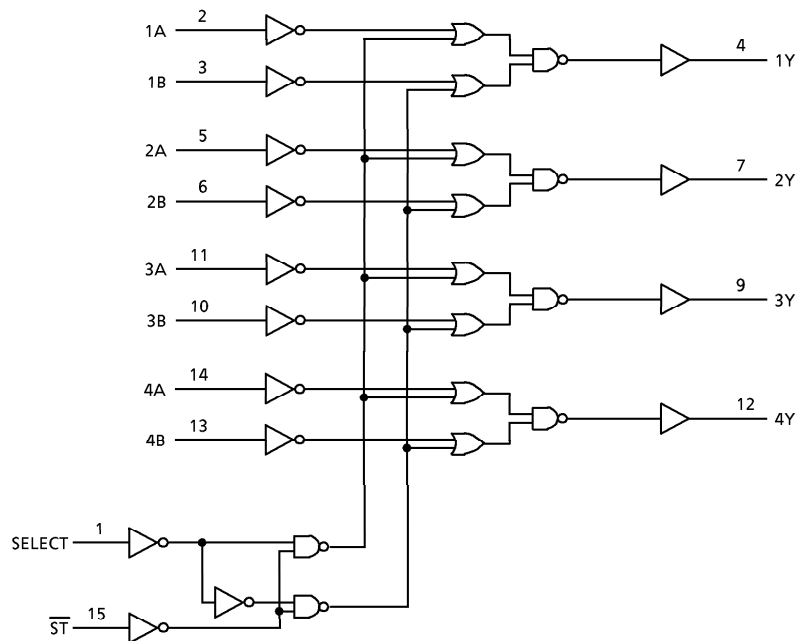
INPUTS				OUTPUTS
\overline{ST}	SELECT	A	B	Y
H	X	X	X	L
L	L	L	X	L
L	L	H	X	H
L	H	X	L	L
L	H	X	H	H

X: Don't Care

IEC Logic Symbol



System Diagram



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- The information contained herein is subject to change without notice.

Maximum Ratings

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~7.0 (Note 1)	V
		-0.5~ V_{CC} +0.5 (Note 2)	
Input Diode Current	I_{IK}	-50	mA
Output Diode Current	I_{OK}	±50 (Note 3)	mA
DC Output Current	I_{OUT}	±50	mA
Power Dissipation	P_D	TBD	mW
DC V_{CC} /Ground Current	I_{CC}/I_{GND}	±100	mA
Storage Temperature	T_{stg}	-65~150	°C

(Note 1): $V_{CC}=0V$

(Note 2): High or Low State. I_{OUT} absolute maximum rating must be observed.

(Note 3): $V_{OUT}<GND$, $V_{OUT}>V_{CC}$

Recommended Operating Conditions

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2.0~3.6	V
		1.5~3.6 (Note 4)	
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output Current	I_{OH}/I_{OL}	±24 (Note 7)	mA
		±12 (Note 8)	
Operating Temperature	T_{opr}	-40~85	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 9)	ns/V

(Note 4): Data Retention Only

(Note 5): $V_{CC}=0V$

(Note 6): High or Low State

(Note 7): $V_{CC}=3.0\sim 3.6V$

(Note 8): $V_{CC}=2.7\sim 3.0V$

(Note 9): $V_{IN}=0.8\sim 2.0V$, $V_{CC}=3.0V$

Electrical Characteristics

DC Characteristics (Ta = -40~85°C)

PARAMETER		SYMBOL	TEST CONDITION		V _{CC} (V)	Min	Max	UNIT
Input Voltage	"H" Level	V _{IH}			2.7~3.6	2.0	—	V
	"L" Level	V _{IL}			2.7~3.6	—	0.8	
Output Voltage	"H" Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100μA	2.7~3.6	V _{CC} - 0.2	—	V
				I _{OH} = -12mA	2.7	2.2	—	
				I _{OH} = -18mA	3.0	2.4	—	
				I _{OH} = -24mA	3.0	2.2	—	
	"L" Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100μA	2.7~3.6	—	0.2	
				I _{OL} = 12mA	2.7	—	0.4	
				I _{OL} = 16mA	3.0	—	0.4	
				I _{OL} = 24mA	3.0	—	0.55	
Input Leakage Current		I _{IN}	V _{IN} = 0~5.5V		2.7~3.6	—	±5.0	μA
Power Off Leakage Current		I _{OFF}	V _{IN} / V _{OUT} = 5.5V		0	—	10.0	μA
Quiescent Supply Current		I _{CC}	V _{IN} = V _{CC} or GND		2.7~3.6	—	10.0	μA
			V _{IN} / V _{OUT} = 3.6~5.5V		2.7~3.6	—	±10.0	
Increase In I _{CC} Per Input		ΔI _{CC}	V _{IH} = V _{CC} - 0.6V		2.7~3.6	—	500	μA

AC Characteristics (Ta = -40~85°C)

PARAMETER		SYMBOL	TEST CONDITION		V _{CC} (V)	Min	Max	UNIT
Propagation Delay Time (A, B-Y)	t _{pLH} t _{pHL}	(Fig.1, 2)			2.7	—	6.3	ns
					3.3 ± 0.3	1.5	5.8	
Propagation Delay Time (SELECT-Y)	t _{pLH} t _{pHL}	(Fig.1, 2)			2.7	—	8.0	ns
					3.3 ± 0.3	1.5	7.0	
Propagation Delay Time (ST-Y)	t _{pLH} t _{pHL}	(Fig.1, 2)			2.7	—	8.0	ns
					3.3 ± 0.3	1.5	7.0	
Output To Output Skew	t _{osLH} t _{osHL}	(Note 10)			2.7	—	—	ns
					3.3 ± 0.3	—	1.0	

(Note 10): Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic Switching Characteristics ($T_a = 25^\circ\text{C}$, Input $t_r = t_f = 2.5\text{ns}$, $C_L = 50\text{pF}$, $R_L = 500\Omega$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Typ.	UNIT
Quiet Output Maximum Dynamic V_{OL}	V_{OLP}	$V_{IH} = 3.3\text{V}$, $V_{IL} = 0\text{V}$	3.3	0.8	V
Quiet Output Minimum Dynamic V_{OL}	$ V_{OLV} $	$V_{IH} = 3.3\text{V}$, $V_{IL} = 0\text{V}$	3.3	0.8	V

Capacitive Characteristics ($T_a = 25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Typ.	UNIT
Input Capacitance	C_{IN}	—	3.3	7	pF
Output Capacitance	C_{OUT}	—	0	8	pF
Power Dissipation Capacitance	C_{PD}	$f_{IN} = 10\text{MHz}$ (Note 11)	3.3	25	pF

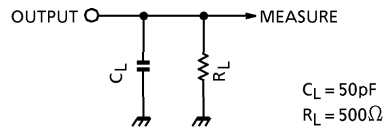
(Note 11): C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

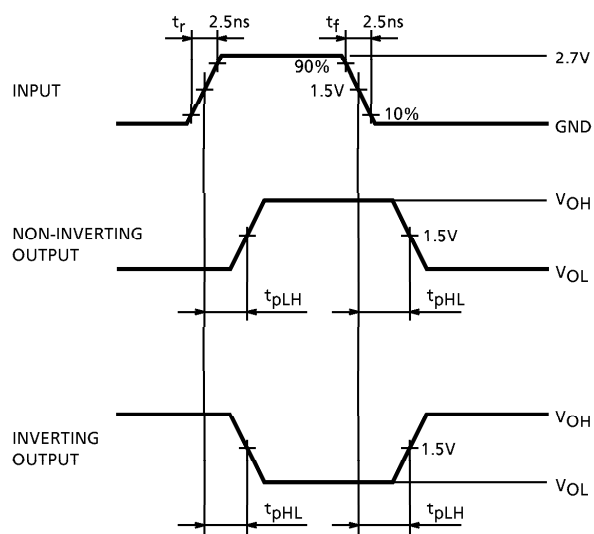
Test Circuit

Fig.1



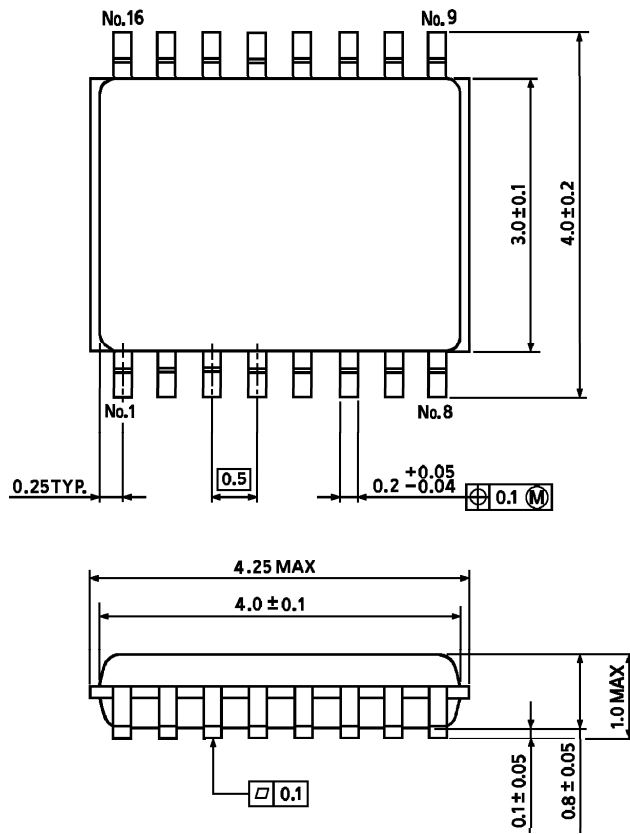
AC Waveform

Fig.2 t_{pLH} , t_{pHL}



Outline Drawing
VSSOP16-P-0030-0.50

Unit: mm



Weight: 0.02g (Typ.)